NANOSECOND PULSE BREAKDOWN STUDY

By

D. F. MCDONALD and M. WALKER

Prepared For

ROME AIR DEVELOPMENT CENTER
RESEARCH AND TECHNOLOGY DIVISION
AIR FORCE SYSTEMS COMMAND
GRIFFISS AIR FORCE BASE
NEW YORK

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EL PASO, TEXAS

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NANOSECOND PULSE BREAKDOWN STUDY

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Rome Air Development Center
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Air Force Systems Command
United States Air Force

Griffiss Air Force Base
New York
ABSTRACT

The theory and most recent experimental work on breakdown under high-power microwave pulses are analyzed. Recommendations are made for further theoretical and experimental investigations to extend this work into the nanosecond region. The feasibility of spectroscopic techniques in the study of discharge growth is considered. It is shown that light emitted during discharge build-up may be of sufficient intensity to allow photometric measurements of the growth rate.

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Nanosecond Pulse Breakdown Study

Daniel F. McDonald
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Griffiss Air Force Base
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FOREWORD

Efforts to increase significantly the peak power levels of pulsed microwave systems have met a number of stubborn technical roadblocks. The demand for greatly increased peak power levels is so great, however, as to justify intense efforts to establish breakthrough techniques in all areas in which these have been encountered.

A well-known limitation of high-power systems is gaseous breakdown. Although much is known of this phenomenon for DC and microsecond pulse systems, breakdown mechanisms have not been studied extensively for the nanosecond pulse case. Since a number of technical considerations suggest improved performance for reduced pulse widths, more intensive theoretical and experimental efforts in the nanosecond region are clearly warranted. This report presents the results of a theoretical investigation of nanosecond microwave discharges and analyses of special diagnostic techniques for experimental studies.
ABSTRACT

The theory and most recent experimental work on breakdown under high-power microwave pulses are analyzed. Recommendations are made for further theoretical and experimental investigations to extend this work into the nanosecond region. The feasibility of spectroscopic techniques in the study of discharge growth is considered. It is shown that light emitted during discharge build-up may be of sufficient intensity to allow photometric measurements of the growth rate.
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INTRODUCTION

Voltage breakdown is a basic phenomenon which can limit the design of high-power microwave transmitting systems. Breakdown may occur in portions of the transmitter plumbing, at the transmitting antenna, or possibly in regions of free space where special conditions of local pressure and microwave power concentration obtain.

A number of experimental and theoretical studies have been conducted on microwave breakdown characteristics in waveguides and antennas. Most of these have considered CW operation or pulses of about 1 μ sec. Many of these studies have considered only complete breakdown, where the impedance change in the breakdown region causes total reflection of the incident microwave power. Some have considered the growth characteristics of the discharge, but both theoretical and experimental information in this area is limited, especially where full breakdown occurs in nanoseconds. It may be possible, however, to take advantage of the finite growth at the discharge and transmit high-power nanosecond pulses before the discharge can go to completion.

To evaluate the possibility of transmitting high power levels during the formative time of the discharge, theoretical analyses of the discharge initiation and growth processes are required. In addition, experimental investigations using nanosecond pulses are also needed and these will require special experimental techniques. This report presents the results of theoretical investigations of the temporal growth of the discharge and studies of the feasibility of special diagnostic techniques for use in experimental work with nanosecond pulses.
I. THEORY OF DISCHARGE GROWTH

Theoretical and experimental work over the past 15 years has led to a basic understanding of the growth characteristics of microwave discharges. This applies particularly to the case of the low pressure, DC and microsecond pulse region. This section presents the mathematical model of breakdown which is generally accepted. The applicability of this theory to the high-pressure, nanosecond pulse region is then discussed.

A. Assumptions

Most theoretical approaches to the analysis of the growth of the microwave discharge are based on the assumption that the free electron density in the discharge is controlled by three processes:

1. Primary ionization of the gas by free electrons -- electron motion under field acceleration produces positive ions and free electrons, adding to the electron density.

2. Electron attachment to neutral molecules - this removes free electrons from the discharge region and forms negative ions.

3. Electron diffusion -- causes loss of free electrons from the discharge region by migration.

Based on these assumptions, a relatively simple model of the breakdown process can be developed. Note that ions are not considered as ionizing agents. This is due to the low mobilities of ions compared with electrons. Caution in neglecting ions as ionizing agents may be warranted in cases where extremely high electric fields are involved.
B. Discharge Growth Equation

Using the assumptions given in Section A, the following partial differential equation may be written, expressing the instantaneous rate of change of free electron density, $n$, as a function of position and time:

$$\frac{\partial n}{\partial t} = \nu_i n - \nu_a n + \nabla^2 Dn$$  \hspace{1cm} (1)

where

- $t$ - time in sec
- $n$ - free electrons/cm$^3$
- $\nu_i$ - ionization frequency
- $\nu_a$ - attachment frequency
- $D$ - diffusion coefficient in cm$^2$/sec

For simple cases, this equation may be solved. One case in which the electric field configuration is similar to that of practical cases is that of a uniform field between plane parallel plates. It is shown in Figure 1a. The TE$_{10}$ mode for rectangular guide is shown in Figure 1b for comparison. For the field of Figure 1a, the electron density is a function of $t$ and $x$ only. Equation (1) may be solved by assuming a solution of the form

$$n(x,t) = T(t) X(x)$$  \hspace{1cm} (2)

where $T$ is a function only of $t$ and $X$ is a function only of $x$.

Substituting Equation (2) in Equation (1) and separating variables leads to the following two ordinary differential equations:
Figure 1a - Uniform field between parallel plates

Figure 1b - TE\textsubscript{10} Mode in rectangular guide
\[ \frac{dT}{dt} = (v_1 - v_2 + C) \quad T \quad (3) \]

\[ \frac{d^2X}{dx^2} = \frac{C}{D} \quad X \quad (4) \]

where \( C \) is the separation constant.

Particular solutions of these equations are:

\[ T = T_k e^{\int (\nu_1 - \nu_2 - \frac{k^2}{D}) dt} \quad (5) \]

\[ X = B_k \sin \frac{k \pi x}{d} \quad (6) \]

In these solutions the boundary conditions \((n = 0 \text{ at } x = 0 \text{ and } x = d)\) are met by making \( C = \frac{2 \nu_1 - \nu_2}{d^2} \) and \( k \) always an integer.

From the particular solutions a general solution may be formed as follows:

\[ n(x, t) = \sum_{k=1}^{\infty} T_k B_k e^{\int (\nu_1 - \nu_2 - \frac{k^2}{D}) dt} x \sin \frac{k \pi x}{d} \quad (7) \]

This may be written as

\[ n(x, t) = e^{\int (\nu_1 - \nu_2) dt} \sum_{k=1}^{\infty} A_k e^{-\frac{k^2 \pi^2 D}{d^2}} \sin \frac{k \pi x}{d} \quad (8) \]

where \( A_k = T_k B_k \).
If the initial electron distribution, $n$, is uniform, it may be shown that

$$A_k = \frac{4n_0}{\pi} \text{ for } k = 1, 3, \ldots$$

and

$$A_k = 0 \text{ for } k = 2, 4, \ldots$$

Thus $n$ may finally be written as

$$n(x,t) = \frac{4n_0}{\pi} \int_0^t (t_1 - t_2) dt - \frac{\pi^2 P c}{\alpha^2} \sum_{k=1} A_k \frac{\sin \frac{k\pi x}{\alpha}}{k^2}$$

(9)

Inspection of Equation (9) shows that the higher modes in the density distribution reduce sharply in importance as time progresses. In the analysis presented in Reference 4, only the fundamental mode is considered, giving $n$ as

$$n = \frac{4n_0}{\pi} \int_0^t (t_1 - t_2) dt - \frac{\pi^2 P c}{\alpha^2} \sin \frac{\pi x}{\alpha}$$

(10)

Thus the density distribution at any point, $x$, grows with time for the case of

$$\int_0^t (t_1 - v_a) dt - \frac{\pi^2 P c}{\alpha^2} > 0$$

(11)
In considering breakdown under pulse, the Equation (10) is extremely useful, since it allows the determination of the time taken to reach the critical electron density, \( n_b \), at which significant microwave energy is reflected from the discharge volume. This electron density is reached at a time \( t_b \) where

\[
\int_{0}^{t_b} (\nu_i - \nu_a) dt = -\frac{n_b^2 \rho}{\pi} t_b
\]

(12)

If this time involves several cycles of rf, then we may write

\[
\int_{0}^{t_b} (\nu_i - \nu_a) dt \equiv <\nu_{\text{net}}> t_b
\]

(13)

where \(<\nu_{\text{net}}>\) is the average value of \( \nu_i - \nu_a \) over a full cycle of rf and represents the average net ionization.

To analyze quantitatively the growth characteristics for a particular gas and a particular microwave power level, the value of \(<\nu_{\text{net}}>\) must be determined. This may be done by determining the variation of electron energy over a full cycle for the given conditions of pressure and peak field strength. When this is known, the variation of \(<\nu_{\text{net}}>\) over a complete cycle of rf may be determined from available DC measurements of these quantities. Finally, the values of the diffusion coefficient, \( D \), can be determined from the well-known relationship

\[
D = \frac{2}{3} \mu_i
\]
where $u$ and $\mu$ are the electron energy and mobility respectively.

C. Theoretical Predictions for Breakdown in Air

In work supported by the Bureau of Ships under Contract NObsr-63295, Gould and Roberts at Microwave Associates, Inc. have carried out the calculations of $v_{\text{net}}$ for a number of values of $E/p$, where $E$ is the electric field strength in volts/cm and $p$ is the pressure in mm Hg. They assumed that breakdown occurs when $n_0/n_i$ is equal to $10^8$. With this information and the diffusion constant, $D$, they were able to establish theoretical breakdown curves for various pulse widths, pressures, and electrode spacing using Equation (10).

The work of Gould and Roberts is summarized in the HANDBOOK ON BREAKDOWN OF AIR IN WAVEGUIDE SYSTEMS published by Microwave Associates, Inc. in April, 1956. A graph taken from that document is reproduced in this report under Figure 2. The information on this graph is used directly to calculate the breakdown field intensity for pulses of various widths and the $TE_{10}$ mode in rectangular guide. The field configuration for this mode is similar to that assumed in the theoretical breakdown model.

Using the information presented in Figure 2, it is possible to compare the breakdown power levels predicted by theory for microsecond versus nanosecond pulse widths. This has been done for the case of a rectangular guide type RG-48, microwave frequency of 2.8 kmc, and air at atmospheric pressure. The results are as follows:

Case 1 - Pulse Width - 1.0 microseconds
Breakdown at 12.2 megawatts

Case 2 - Pulse Width - 3 nanoseconds
Breakdown at 93.5 megawatts
Figure 2 - Theoretical normalized single pulse breakdown curves.
The comparison of the results of these two cases shows that theory does indeed predict a considerable improvement in the peak power capabilities for nanosecond versus microsecond pulses. These power levels are unusually high compared with those typically listed with standards for waveguides. Listed ratings are based on CW operation and the breakdown rating of 10 kv/cm rms field strength. For RG-48 guide, these criteria lead to CW power ratings of about 3 megawatts.

From the theoretical model and its predictions, it is clear that considerably greater peak power may be transmitted as pulse widths are reduced toward the nanosecond region. This result is very promising and suggests further refinements in the mathematical model of breakdown, as well as more intensive experimental verifications of its predictions. Some of the experimental work which has been done is discussed in the following sections.

D. Experimental Studies of Pulse Breakdown

Gould and Roberts\(^4\) have reported the results of experimental microwave pulse breakdown studies. These studies used pulse widths of 0.8, 2.5 and 4.0 microseconds at a frequency of 2.8 KMC. The test cell in which breakdown was measured was a cylindrical microwave cavity whose height was 0.635 centimeters. Pressures were varied from 21 to 1600 millimeters Hg.

The experimental results of Gould and Roberts agrees well with their theoretical curve. The use of a high-Q resonant cavity and short pulses does warrant some comment. The cavity used had a Q of 1,000.* This implies a cavity filling time of 0.06 \(\mu\) sec for the frequency used. The energy in the cavity as a function of the time of application of the pulse is given approximately by

\[^*\text{L. W. Roberts, Private Communication, 1 April 1963}^\]
The electric field intensity, which is of more direct interest, is related to energy density as follows

\[ E \sim (P_1 \tau)^{1/2} (1 - e^{-\frac{t}{2\tau}})^{1/2} \]  

For the case of \( Q = 1,000 \) and \( f = 2.8 \text{ kmc} \) the value of \( \tau \) is 0.06 \( \mu\text{sec} \). For the shortest pulse width (0.8 \( \mu\text{sec} \)) used by Gould and Roberts, cavity rise time is short compared to the pulse rise time. The rise time of the energy density in the cavity is then determined by the pulse rise time alone. If work is to be done with nanosecond pulses, considerably shorter values of \( \tau \) must be employed. It may develop that the cavity resonator technique is not suitable from this point of view.

Where cavity resonator techniques are used, the electric field intensity within the cavity is determined indirectly from measurements of other parameters in the experimental system. Gould and Roberts do not make explicit reference to this in their publication but it is presumed these techniques were used. It should be noted that since energy stored in the cavity depends on \( P_1 Q \) that accurate measurements of \( Q \) are indeed very important.

Another point which should be mentioned is the guide-cavity coupling. This involves stubs and apertures. Since these represent a departure from the ideal geometry of the cavity, breakdown may occur at the edges of apertures or stubs. This effect could yield lower breakdown values than the ideal case.
The work of Gould and Roberts says much about pulse breakdown and deserves close critical attention. It is a point of departure for nanosecond breakdown studies, but much further experimental work is needed. This work should emphasize:

1. Pulse widths of 1 to 100 ns
2. Improved test cell techniques
3. Increased effort to record breakdown growth

E. High Field Values of V_{net}

In the preceding discussions, it was emphasized that the values of V_{net} determined the breakdown growth rate. To calculate values of V_{net}, the instantaneous values of the electron energy u are required. The differential equation determining u is

\[ \frac{du}{dt} = \frac{\mu E_0^2}{1 + (\omega/\nu_c)^2} \left[ \sin^2 \omega t - \frac{\omega}{2\nu_c} \sin \omega t \right] - K \rho \mu \]

where E is the peak field value, \( \nu_c \) is the collision frequency and K is the fractional energy loss/sec - mm Hg. For a particular gas this equation is integrated numerically, relating u to the phase of the microwave field. Then from DC measurements, both \( \nu_i \) and \( \nu_a \) are related to u and hence to the phase of the microwave field. The values of \( \nu_i - \nu_a \) are then averaged over one cycle to yield a value of \( \langle V_{net} \rangle \).

For the microwave power levels under consideration, the peak values of the electric field may be 60,000 volts/cm or even greater. None of the DC experiments used to measure ionization and attachment coefficients use such high fields. Usually, field intensities of a few hundred volts/cm are employed. The DC data, however, are presented as functions of
the ratio $E/p$. It is assumed that the data apply to this ratio, regardless of the absolute value of $E$. Thus, for example, a measurement made at 250 volts/cm and 5 mm Hg is assumed to apply to the case of 50,000 volts/cm and 1,000 mm Hg. This extrapolation certainly warrants considerable scrutiny.

**F. Breakdown in Sulphur Hexafluoride**

Air and sulphur hexafluoride are the most widely used dielectric gases. The characteristics of sulphur hexafluoride suggest that it would have an unusually low value of $\langle v_{\text{net}} \rangle$ and that much higher breakdown power levels with sulphur hexafluoride would be realized than are realized with air. Considerable work has been done comparing breakdown in air with breakdown in $SF_6$. It would be useful to apply the breakdown theory presented in the preceding sections to $SF_6$.

Some of the material on $SF_6$ attachment and ionization coefficients and other characteristics which was developed during this study is presented in the Appendix.
II. NATURAL ELECTRON DENSITY AND BREAKDOWN INITIATION

In all theories of microwave and DC gas discharges, it is assumed that there is an initial electron or an electron concentration in the gas volume under study. The initial free electron or free electrons become the agents which first produce increasing ionization in the gas under the action of the electric field. These initial free electrons are produced by external agencies such as radioactive material and cosmic radiation. The relationship of electron density and discharge initiation is discussed in this section.

A. Natural and Artificial Conditions

For the case where experimental studies of breakdown are conducted without the use of auxiliary radiation sources such as Cobalt 60, considerable statistical lags are observed in the initiation of microwave discharges. In most pulse studies, this statistical effect manifests itself as an intermittent breakdown effect. Breakdown occurs only for a fraction of the total number of pulses transmitted. For those pulses in which breakdown does not occur, it is assumed that free electron concentration in the volume under study was not at sufficient levels during the pulse period to lead to breakdown.

In other laboratory experiments on microwave discharges, high initial electron concentrations are artificially induced using Cobalt 60 or other sources of radioactivity. These radioactive sources may raise initial electron concentration levels as high as \(10^3\) electrons per cc. In the experimental work of Gould and Roberts, this technique eliminated statistical fluctuation in breakdown initiation and permitted
correlation of observed breakdown and the theory which assumes high initial electron concentrations. This, therefore, was a laboratory experiment which may not have been realistically related to the field case.

The mechanism of discharge initiation and the statistics associated with it may be basic to the investigation of techniques for transmitting super-power nanosecond microwave pulses. For example, in going from the microsecond pulse widths to the nanoseconds pulse widths, the probability of transmitting pulses without breakdown improves by a factor of 100 to 1000.

B. Analysis of Free Electron Concentration

In the absence of an artificial ionizing radiation source, free electron concentrations in a gas sample are extremely low. It is generally assumed that those which do exist are due to the high energy radiation in cosmic rays and natural radioactivity in the walls of the test chamber. In most cases, the ionizing agents in the gas sample are secondary electrons ejected from the walls into the chamber by the high energy radiation. These electrons ionize the molecules of the gas. In the case of air, this results in the formation of ions at the rate of about 10 ion pairs/cm$^3$ - sec. Free electrons generally appear in groups numbering from 1 to 10 electrons. Thus, there are one or two ionizing events /cm$^3$ - sec in a specimen volume, each event contributing about 5 electrons.
When ionization occurs, an electron is ejected from one of the constituent molecules of the gas, forming a positive ion and a free electron. In most cases, the free electron quickly attaches itself to a neutral molecule forming a negative ion. This will normally occur in times of $10^{-7}$ seconds or much less. The resulting ions have much longer lives lasting for times of the order of ten's to hundred's of seconds.

It is interesting to estimate the expected lifetime of free electrons due to high-energy radiation in a typical waveguide structure such as RG-48. Estimates of this lifetime may be arrived at as follows:

For free electrons whose energies are between 0 and 2.0 electron volts, the average attachment coefficient is about $2 \times 10^{-5}$/collision. At one electron volt, the electron speed is $6 \times 10^7$ cm/sec. At atmospheric pressure, it experiences about $3 \times 10^4$ collisions per centimeter. Thus, on the average, a free electron will travel 1.7 cm before attaching. It travels the distance in the time of $3 \times 10^{-8}$ sec.

For free electrons with energies between 2.0 and 50,000 volts, in air the average ranges are a few centimeters and average speeds of about $5 \times 10^8$ cm/sec. Thus, the time for the electron energy to fall to 2.0 volts or less is about $10^{-8}$ seconds.

For free electrons with energies above 50,000 volts, the ranges vary from a few cms to meters. Speeds are near the speed of light. Thus, these electrons pass through the discharge chamber into a wall in a few nanoseconds.
From these order of magnitude calculations, it appears that free electron lifetimes are of the order of $10^{-8}$ sec in a typical waveguide at atmospheric pressure. *

Taking $10^{-8}$ sec as the lifetime of a free electron at atmospheric pressure and assuming that there are only 2 ionizing events/sec/cm$^3$, it is clear that there is a low probability that free electrons will be present during a short pulse. For a microwave pulse, of width $T$ which is large compared to $10^{-8}$ sec, it may be shown that the probability of free electrons being available to initiate discharge during the pulse period is approximately

$$P = 2VT$$

where $V$ is the volume of the discharge chamber and there are two ionizing events/cm$^3$.

Taking this as a probability of breakdown, we can calculate $P$ for typical cases. In the work of Gould and Roberts, the volume of the test cell was about 6 cm$^3$. Pulse widths were 0.8, 2.5, and 4.0 µsec. This leads to probability of breakdown of the order of $2 \times 10^{-5}$ breakdown/pulse

Gould and Roberts observed, however, that the breakdown probability was $10^{-3}$.

*This is order of magnitude only and it is noted that published estimates, e.g., by Compton and Langmuir, Rev. Mod. Phys. 2,193 (1930) are between $10^{-6}$ and $10^{-7}$ sec.
It is very important to investigate this difference between the expected and observed probability of breakdown. This investigation should include the following:

1. Examination of the role of ions in initiating discharge
2. Role of surface effects
3. Role of contaminants such as dust

In general, a much deeper understanding of how breakdown occurs may lead to techniques to inhibit the initiating process. Such techniques may be concerned with surface conditions, contaminants, reducing radioactive content of materials, or other factors. They could be used to improve greatly the statistical probability of transmitting super-power pulses of nanosecond widths.
III. DIAGNOSTIC TECHNIQUES IN DISCHARGE INVESTIGATIONS

A. Introduction

The experimental techniques used typically in studying the growth of microwave discharges have provided limited information about the temporal growth of the discharge. Measurements of reflected microwave energy have yielded information on the average free electron density in the discharge region. Improved nanosecond pulse techniques should lead to more detailed information in this area.

In this section, the feasibility of spectroscopic techniques is considered. Used successfully, these could contribute considerably more information about the increasing concentration of ion populations and the spatial distribution of the discharge in the test volume.

Both absorption and emission spectroscopy are considered.

B. Absorption Spectroscopic Techniques

For microwaves of wavelength \( \lambda \), the discharge region becomes highly reflecting when the electron density reaches or exceeds the critical level, \( n_b \), given as

\[
    n_b = \frac{10^{13}}{\lambda^2} \text{ electrons/cm}^3
\]

where \( \lambda \) is in cms. Thus, at 3kmc, the critical level is

\[
    n_b = 10^{11} \text{ electrons/cm}^3
\]
In the high-power nanosecond pulse case of interest here, the discharge will reach this level in $10^{-8}$ sec. In Section II, it was shown that free electron average lifetimes are of this order. Ion lifetimes are much longer. It then follows that when breakdown electron concentration is reached, the discharge region contains

$10^{11}$ electrons/cm$^3$

$10^{11}$ positive ions/cm$^3$

The positive ions are both $O_2^+$ and $N_2^+$ with the latter predominating.

To estimate the effectiveness of spectroscopic absorption techniques in measuring ion concentrations, the absorption cross-sections for $O_2^+$ and $N_2^+$ are needed. These are not readily available but, by assuming unusually favorable absorption characteristics, it is possible to show that a practical absorption technique is not possible.

Assume that the ions in the discharge have large cross-sections, around $10^{-19}$ cm$^2$, and absorption spectra located in the visible. Then the absorption of a test beam of intensity $I$ is given by

$$\frac{dI}{I} = -\sigma \rho dx$$

where $\sigma$ is the absorption cross-section and $\rho$ is the ion density. For the values of $\sigma$ and $\rho$ which apply here this yields

$$dI = -10^{-8} dx$$

Thus, for a path length of 10 cms, as long as is practical, this yields

$$\frac{dI}{I} = -10^{-7}$$
The measuring photometer (probably a photomultiplier) must have a response time of about 1 ns to suitably resolve the experimental pulse rise. Thus in calculating signal-to-noise ratios, the signal sampling time is taken as 1 ns. If \( N \) is the total number of photons which pass through the test region in that time, then the signal \( S \) is the amount absorbed or

\[
\text{Signal} = N \times 10^{-7}
\]

The photon shot noise is given as

\[
\text{Noise} = \sqrt{N}
\]

Therefore

\[
\frac{\text{Signal}}{\text{Noise}} = 10^{-7} \sqrt{N}
\]

Let us assume this value to be 5 or greater; that is, the signal is fairly readable above the noise. Then we have that

\[
N = 2.5 \times 10^{15} \text{ photons}
\]

Since this number must pass through absorption region in 1 ns, this requires a beam intensity \( I \) of

\[
I = \frac{N}{1 \text{ ns}} = 2.5 \times 10^{24} \text{ photons/sec}
\]

Assuming a photon energy of \( 2.5 \times 10^{-19} \) joules, this corresponds to an input peak light power of

\[
P_i = 100 \text{ kw}
\]

Note that this does not allow for light collection or photon detection efficiency. When this is taken into account, the peak light power
requirement is 10 MW or greater. This is an extremely high light power level and would require a laser source. Since these calculations are based on the most favorable considerations, it appears that the absorption spectroscopic techniques required for diagnostic studies are well beyond the state of the art.

C. Emission Spectroscopy

It is well known, of course, that there is strong emission of light from a microwave breakdown. Most of this emission, however, is associated with complete breakdown. There is considerably less during breakdown growth. Analysis is presented in this section of the feasibility of using the emission during growth to record the growth rate.

In Section I, the expression, Equation 10, developed for the free electron density at the center of the gap during discharge growth may be written

\[ n = \frac{4n_0}{\pi} e^{\langle \gamma_{net} \rangle t} \]

where high pressures (760 mm Hg) are assumed and diffusion losses are negligible.

In the cases of interest breakdown occurs at \( t \sim 10^{-8} \) sec. Let us assume that the specimen gas is artificially ionized by Co\textsuperscript{60} as in the case of Gould and Roberts' work. This gives values of \( n_0 \) of \( 10^2 \) to \( 10^3 \). Results of this analysis are not too sensitive to this parameter and \( 10^2 \) is arbitrarily selected as the value of \( \frac{4n_0}{\pi} \). Thus we have at breakdown
\[ 10^{11} = 10^2e + \nu_{\text{net}} \times 10^{-8} \]

This yields a value of \( \nu_{\text{net}} \) of

\[ \nu_{\text{net}} = 10^8 \ln 10^9 \]

\[ \nu_{\text{net}} = 2 \times 10^9 \text{ ionization/sec-electron} \]

Thus, we have the free electron density expressed as

\[ n = 10^2e 2 \times 10^9t \]

If the air fluorescence decay time is longer than a few nanoseconds, it will severely limit the resolution required in measuring growth rate. However, it has been measured as 2.0 ns at atmospheric pressure by several experimenters. Thus, it may be used directly to measure growth rate without serious error. Since the decay of air fluorescence is exponential, analytic techniques can be used to "subtract out" the effects of fluorescence lifetime in the recorded signal and yield more accurate growth measurements.

Next it is necessary to estimate the light power output from the discharge region. This may be done by determining the power absorbed by the region from the microwave field. At atmospheric pressure and peak field intensities of 40,000 \text{ v/cm}, the average velocity of free electrons, \( \nu_d \), is

\[ \nu_d = 10^6 \text{ cm/sec} \]
\[10^{11} = 10^2 e + \nu_{\text{net}} \times 10^{-8}\]

This yields a value of \(\nu_{\text{net}}\) of

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\[v_d = 10^6 \text{cm/sec}\]
This gives a current density, \( J \), of

\[ J = e v_d \]

where \( e \) is the electronic charge. The power absorbed per \( \text{cm}^3 \), \( P_v \), is then given by

\[ P_v = jE = e v_d En = e v_d E_n e V_{\text{net}} t \]

For the parameters used here this becomes

\[ P_v = 4.7 \times 10^{-6} \text{ watts/cm}^3 \quad (1 \text{ ns}) \]

\[ P_v = 3.1 \times 10^2 \text{ watts/cm}^3 \quad (10 \text{ ns}) \]

To determine the light output per \( \text{cm}^3 \), it is necessary to determine the conversion efficiency from electrical input power to light output power. McDonald and Dunn* estimated this as \( 10^{-5} \) on the basis of work done with 20kv electrons and air at atmospheric pressure. Although it is not certain that this applies to low voltage electrons as well, it will be used here for the purpose of estimation. Thus, light output power/cm\(^3\) is

\[ P_L = 4.7 \times 10^{-11} \text{ to } 3.1 \times 10^{-3} \text{ watts/cm}^3 \quad (1 \text{ ns to } 10 \text{ ns}) \]

This corresponds to about

\[ 0.1 \text{ to } 10^7 \text{ photons per nanosecond/cm}^3 \quad (1 \text{ ns to } 10 \text{ ns}) \]

*Unpublished
For sample volumes of 10 cm$^3$ and good collection efficiency, photomultiplier recording should begin to measure light output in 2 or 3 ns from the initiation of the discharge. As the discharge approaches complete breakdown, light signal levels will be easily recorded.
IV. CONCLUSIONS

Conclusions

In the preceding sections, analyses were presented of the microwave pulse breakdown theory, experiments, and diagnostic techniques applicable to nanosecond breakdown studies. The following conclusions are drawn from the results of these analyses.

1. Current theory and experiment provides a satisfactory understanding of the discharge growth in the high-power microsecond pulse region.

2. The results of current theory and experiment may be extrapolated to the nanosecond high-power pulse region, but experimental work using high-power nanosecond pulses directly is needed to verify theory for ultra-short pulses.

3. Test cell techniques may be a source of error in experimental work with pulse breakdown. Special experimental effort is required in this area.

4. Theoretical and experimental study of the ionization and attachment coefficients under high-field, high-pressure conditions is needed to provide a check on currently used values. Current values are determined under low-field, low-pressure conditions.

5. More theoretical analysis is required to establish the lifetimes and natural concentrations of free electrons in air and other gases. The mechanism of discharge initiation requires detailed investigations in this area and perhaps others.

6. Emission spectroscopic techniques may be feasible for studies of the discharge growth rate.
APPENDIX

Note on Sulphur Hexafluoride

The theory of microwave breakdown presented in Section I applies to all gases. As was shown in the development of that theory, the value of the average net ionization coefficient $\langle \nu_{\text{net}} \rangle$ determined the rate at which breakdown proceeds. This theory was applied to the case of air which is of special interest because it is used commonly in filling waveguides. The other gas which is also often used is sulphur hexafluoride (SF$_6$).

Sulphur hexafluoride has unusual properties which make it a particularly effective dielectric gas. In particular, it is electronegative; i.e., it has a high attachment cross-section. Thus, the value of $\nu_a$ can be very high and at the same time, the ionization coefficient, $\nu_i$, is very low. Thus, $\nu_{\text{net}}$ is generally very small. Discharge growth is prevented or proceeds at a rate much slower than for air under the same power levels. Aspects of SF$_6$ considered during the breakdown study are presented here.
Electron Attachment in SF$_6$

This section covers the present knowledge of processes occurring upon collision between electrons and SF$_6$ - atoms and ions.

Figure 3 shows the octahedral symmetry of the SF$_6$ molecule, and its approximate dimensions. The normal valence of sulfur, 4, has been extended to 6, possibly indicating some fractional bond energy remaining between the fluorine atoms. Both bonds, the S-F and the possibly remaining F-F portion, are covalent; i.e., they are due to electron pair exchange forces. The bond energy of the S-F bond is estimated to 100 K cal mol$^{-1}$ following data presented by Pauling. This yields a total bond energy of approximately 500 K cal mol$^{-1}$, assuming some reduction of the SF bond energy due to the valence increase from 4 to 6. By comparison, the bond energies of other compounds featuring high strength bonds are:

- H - F = 147 K cal mol$^{-1}$
- F - F = F$_2$ 63.5 K cal mol$^{-1}$
- H - O = 220.3 K cal mol$^{-1}$
- H - F = H$_2$, 103.4 K cal mol$^{-1}$

The above data show that the bond energy of the SF$_6$ molecule is very high and the molecular structure is a highly symmetrical dense package, exposing only strongly electronegative fluorine atoms on its surface. These properties are largely responsible for the high stability, chemical inertness (all bond-providing electron pairs are fully occupied within the molecule), and electron-attaching properties. The simplicity and symmetry of the bond structure, in conjunction with the
Octahedral arrangement of fluorine atoms

Approximate attachment cross-section

Fig 3. Approximate Dimensions of SF₆ Molecule.
high bond strength, are probably responsible for the very small permanent and the low value of the induced dipole moment of SF₆.

The above information provides some understanding of the chemical and physical properties of SF₆ but indicate little towards its gaseous electronics properties. A few basic properties described above are borne out qualitatively, like the strong electron-attaching properties which can be expected from the dense highly symmetrical package of electronegative fluorine atoms surrounding the central sulfur atom. The chemical inertness suggests low decay rates in the hot environment of spark or arc discharges. Both properties are exhibited in a rather striking manner. The attachment cross-section of SF₆ for slow electrons is one of the highest known, 6 x 10⁻¹⁶ cm², which is approximately equal to the total cross-sectional area of the molecule (Figure 4). Decay rates in spark discharges through SF₆ have been found to be extremely small by one of its manufacturers. Only 5% of the gas was decomposed after 5 h of continuous arcing in a waveguide.

The large attachment cross-section means that most slow electrons colliding with an SF₆ molecule stick to it, forming an SF₆⁺ ion. Thus, for electrons of thermal energy, the attachment coefficient is likely to be as high as 50%. With increasing electron energies, the attachment coefficient decreases rapidly, as indicated by the ion current measured in pertinent experiments.

According to Fox, no ionization occurs between 2 and 12 ev; at approximately 12 ev, positive ions are first observed. In the region between these two energies there may be some energy transfer between the electrons and the rotational and/or vibrational states of the molecules or ions but not of a magnitude leading to ionization.
Fig. 4. Attachment cross-sections for zero-velocity electrons for electronegative gases.
This means that electronegative gases are effective buildup-inhibitors primarily for very slow electrons. Once the electron has acquired more than a few eV energy, it will not become attached unless it is slowed down again.

Ionizing Collisions and Collision Products

Of the many reactions between free electrons and SF$_6$ molecules, few can lead to carrier multiplication as required for discharge buildup. These reactions are:

$$\text{SF}_6 + e(0-2\text{ev}) \rightarrow \text{SF}_6^- \quad \text{(attachment)}$$

$$\text{SF}_6 + e(2\text{ev}) \rightarrow \text{SF}_5^- + F$$

$$\text{SF}_6 + e(15.85\text{ev}) \rightarrow \text{SF}_4^+ + F^- + e$$

$$\text{SF}_6 + e(18.8\text{ev}) \rightarrow \text{SF}_4^+ + F_2 + 2e$$

Of these reactions, only the last produces electron multiplication and, thus, is the only one which can contribute to discharge growth. There are other less important reactions in addition to those listed but, again, these do not produce electron multiplication.

Since relatively high electron energy is required to produce ionization which leads to charge multiplication, it appears that the ionization coefficient for SF$_6$ is low even under high fields. With a high attachment coefficient, then the value of $\nu_{\text{net}}$ should be unusually low, perhaps lower than is indicated by observed breakdown levels. This indicates a need for more theoretical investigation of SF$_6$ breakdown. It also leads to the speculation that impurity gases
Possible Effects of Impurity Content

The impurities contained in commercial sulfur hexafluoride constitute a substantial partial pressure of non-attaching gases. Both U.S. manufacturers specify a purity of \(98-99\%\) with the remaining \(1-2\%\) consisting of:

- moisture - \(0.014 - 0.002\%\)
- air - \(0.75 - 1.1\%\)
- \(\text{SF}_4\) - \(\sim 0.2\%\)
- so-called "high boilers" - \(0 -0.0005\%\)

Known decomposition products in the presence of air and moisture are:

\[
\text{SOF}_2, \text{SO}_2\text{F}_2; \text{OF}_2, \text{HF; } \text{S}_2\text{F}_10; \text{SF}_4
\]

Assuming 1% contaminant concentration of non-attaching character, this corresponds in 2 atm of \(\text{SF}_6\) to a partial pressure of 15mm Hg. It is curious to note that this is near the Paschen minimum. It may be that the contaminants are the principal participants in the discharge process. Studies of the effects of impurity gases have been made\(^{12,13}\), but these have not been extended to regions of high purity.

*Matheson Co. and Gen. Chem. Corp.

In one case, an unsubstantiated claim of 99.9% purity is made.
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